

SHENZHEN BOND OPTOELECTRONICS CO.,LTD

SPECIFICATION FOR APPROVAL

Customer: _____

Description: _____ SMD LED _____

Model: _____ BDS-0805SGW _____

No.: _____ SD0030 _____

Date: _____ 2006.04.06 _____

Enclosure is the specification

SHENZHEN BOND OPTOELECTRONICS CO.,LTD			
Production Dept.	Quality Dept.	Engineering Dept.	Marketing Dept.

APPROVED SIGNATURES			

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**BDS-0805SGW
SUPER BRIGHT GREEN**

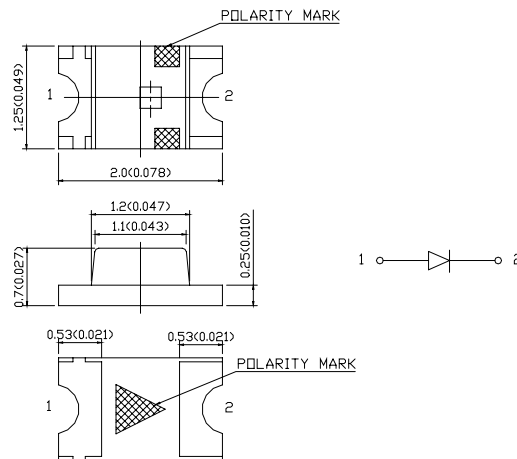
Features

- 1)2.0mmx1.25mm SMT LED, 0.7mm THICKNESS.
- 2)LOW POWER CONSUMPTION.
- 3)WIDE VIEWING ANGLE.
- 4)IDEAL FOR BACKLIGHT AND INDICATOR.
- 5)VARIOUS COLORS AND LENS TYPES AVAILABLE.
- 6)PACKAGE: 3000PCS/REEL.

Description

The Super Bright Green source color devices are made with Gallium Phosphide Green Light Emitting Diode.

Package Dimensions



Notes:

- 1. All dimensions are in millimeters (inches).
- 2. Tolerance is ± 0.1 (0.004") unless otherwise noted.
- 3. Specifications are subject to change without notice.

Selection Guide

Part No.	Device	Lens Type	Iv (mcd) @20mA		Viewing Angle
			Min.	Typ.	2 θ 1/2
BDS-0805SGW	SUPER BRIGHT GREEN <GaP>	White Diffused	4	15	120°

Note:

- θ 1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.

Electrical / Optical Characteristics at TA=25° C

Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ peak	Peak Wavelength	Super Bright Green	565		nm	I _F =20mA
λ D	Dominate Wavelength	Super Bright Green	568		nm	I _F =20mA
$\Delta \lambda$ 1/2	Spectral Line Half-width	Super Bright Green	30		nm	I _F =20mA
C	Capacitance	Super Bright Green	15		P _F	V _F =0V;f=1MHz
V _F	Forward	Super Bright Green	2.2	2.5	V	I _F =20mA
I _R	Reverse Current	Super Bright Green		10	uA	V _R =5V

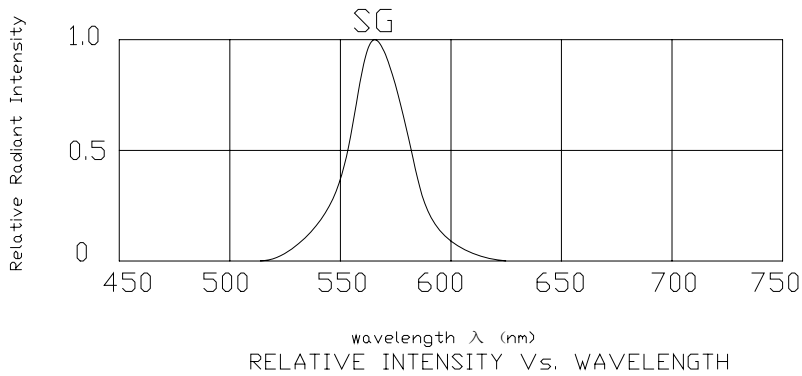
Absolute Maximum Ratings at TA=25° C

Parameter	Super Bright Green	Units
Power dissipation	105	mW
DC Forward Current	25	mA
Peak Forward Current (1)	140	mA
Reverse Voltage	5	V
Operating/Storage Temperature	-40° C To +85° C	

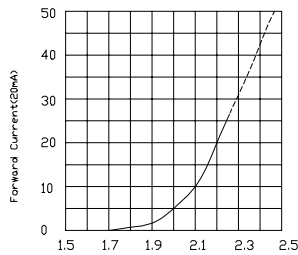
Note:

- 1/10 Duty Cycle, 0.1ms Pulse Width.

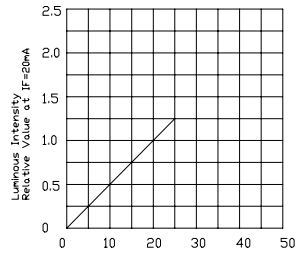
Relative Intensity Vs Wavelength Chart



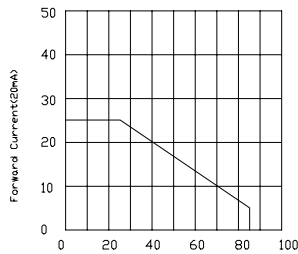
Super Bright Green BDS-0805SGW



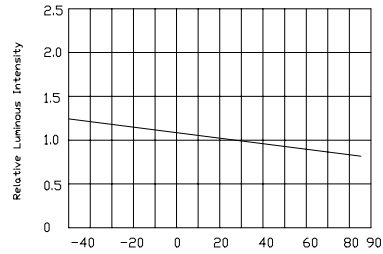
Forward Voltage(V)
FORWARD CURRENT VS FORWARD VOLTAGE
正向电流与正向电压关系曲线图



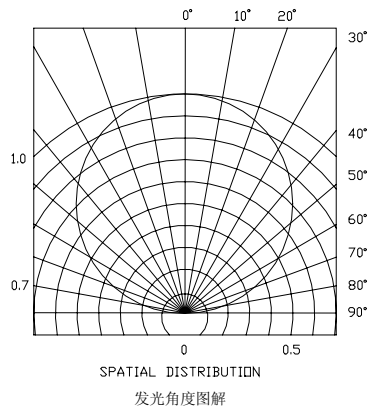
I_f-Forward Current(mA)
LUMINOUS INTENSITY VS FORWARD CURRENT
亮度与正向电流关系曲线图



Ambient Temperature T_a(°C)
FORWARD CURRENT DERATING CURVE
正向电流递减曲线图



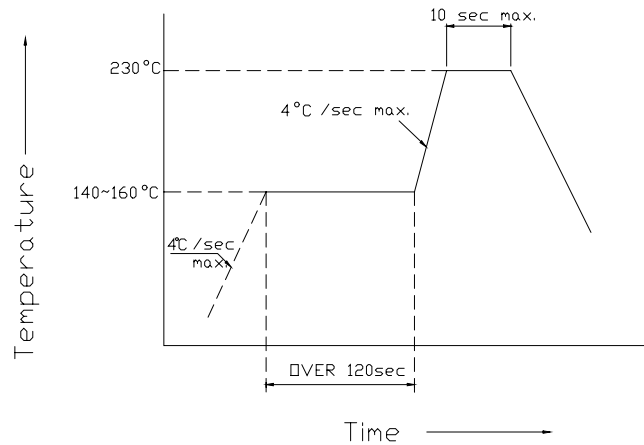
Ambient Temperature T_a(°C)
LUMINOUS INTENSITY VS AMBIENT TEMPERATURE
亮度与环境温度关系曲线图



SPATIAL DISTRIBUTION
发光角度图解

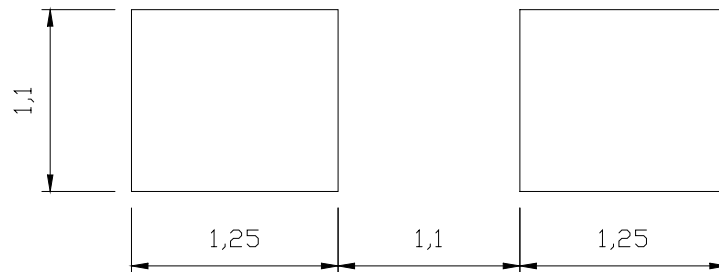
BDS-0805SGW
SMT Reflow Soldering Instructions

Number of reflow process shall be less than 2 times and cooling process to normal temperature is required between first and Second soldering process.



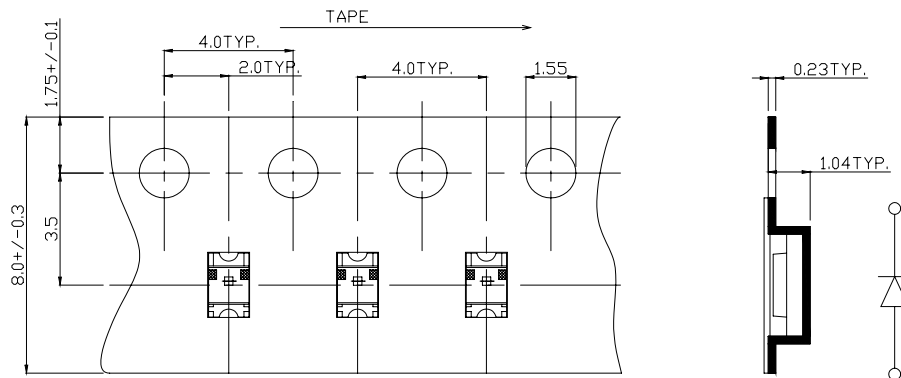
Recommended Soldering Pattern

<Units:mm>



Tape Specifications

<Units:mm>



RELIABILITY**(1) TEST ITEMS AND RESULTS**

Test Item	Standard Test Method	Test Conditions	Note	Number of Damaged
Resistance to Soldering Heat (Reflow Soldering)	JEITA ED-4701 300 301	Tsld=260°C, 10sec. (Pre treatment 30°C,70%,168hrs)	2 times	0/50
Solderability (Reflow Soldering)	JEITA ED-4701 300 303	Tsld=215±5°C, 3sec. (Leader Solder)	1time over 95%	0/50
Thermal Shock	JEITA ED-4701 300 307	-40°C~100°C 5min. 5min.	100cycles	0/50
Temperature Cycle	JEITA ED-4701 100 105	-40°C~25°C~100°C~25°C 30min. 5min. 30min. 5min.	100cycles	0/50
Moisture Resistance Cycle	JEITA ED-4701 200 203	25°C~65°C~-10°C 90%RH 24hrs./1cycle	10 cycles	0/50
High Temperature Storage	JEITA ED-4701 200 201	Ta=100°C	1000 hrs	0/50
Temperature Humidity Storage	JEITA ED-4701 100 103	Ta=60°C, 90%RH	1000 hrs	0/50
Low Temperature Storage	JEITA ED-4701 200 202	Ta=-40°C	1000 hrs	0/50
Steady State Operating Life		Ta=25°C, IF=20mA	1000 hrs	0/50
Steady State Operating Life of High Temperature		Ta=85°C, IF=5mA	1000 hrs	0/50
Steady State Operating Life of High Humidity Heat		60°C, 90%RH, IF=15mA	500 hrs	0/50
Steady State Operating Life of Low Temperature		Ta=-30°C, IF=20mA	1000 hrs	0/50
Drop		H=75cm	3 cycles	0/50
Substrate Bending	JEITA ED-4702	3mm, 5 ± 1 sec.	1 time	0/50
Stick	JEITA ED-4702	5N, 10 ± 1 sec.	1 time	0/50

(2) CRITERIA FOR JUDGING THE DAMAGE

Item	Symbol	Test Conditions	Criteria for Judgement	
			Min.	Max.
Forward Voltage	V _F	I _F =20mA	-	U.S.L.*)X1.1
Reverse Current	I _R	V _R =5V	-	U.S.L.*)X2.0
Luminous Intensity	I _V	I _F =20mA	L.S.L.**)X0.7	-

*) U.S.L.: Upper Standard Level

**) L.S.L.: Lower Standard Level

Intensity And Color Bin Limits

(1) Intensity Bin Limits ($I_F=20mA$)

SELECTION CODE FOR SUPER BRIGHT LEDES		
Group	Light intensity in mcd(20mA)	
	min.	max.
B	2.6	5.5
C	4	10
D	7	15
E	10	24
F	18	44

Tolerance for each Bin limit is ± 0.15 .

(2) Color Bin Limits ($I_F=20mA$)

COLOR CODE FOR LEDES + DISPLAYS		
Group	Dom. WaveLength (nm)	
	Green	
	min.	max.
0	556	559
1	559	561
2	561	563
3	563	565
4	565	567
5	567	569
6	569	571
7	571	573
8	573	575

Tolerance for each Bin limit is ± 0.15 .